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ThalesAlenia a Thates / Leonardo company Space

Silicon Nitride for optical applications

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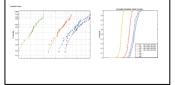
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///<u>Heritage</u>: 2 decades of successful development and operation of extremely stable optical instruments with Si3N4

Materials	Density	Young's Modulus	Poisson's ratio	Max Stress (EN843-5)	Fracture toughness	CTE @ ambient	CTE@ 40 K	Thermal conductivity @ ambient	Specific heat capacity
	ρ (g/cm ³)	E(GPa)	v	MPa	MPa.m ^{0.5}	10 ⁻⁸ /K	10 ⁻⁶ /K	K (W/mK)	C _p (J/kgK)
Si ₃ N ₄	3.25	310	0.3	>630	7.5	1.4	ca 0.01	17 to 50	674

///Mechanical behaviour: thorough test campaigns demonstrated very good reproducibility of the Si₃N₄ manufacturing process, and reliability of the sizing methodology when associated to sound characterization tests.





///Material optimization: increased thermal conductivity

///Thermal conductivity, coefficient and thermal expansion have been confirmed on samples machined directly from <u>scale</u> <u>1 parts</u>.

///Mechanical tests proved again a good <u>reproducibility</u> and <u>homogeneity</u>



/// Next steps: bring those technology improvements to a maturity level allowing new designs and enabling even more ambitious optical performance



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